



达林顿光耦

Darlington Photo Coupler

AT815

Product Data Sheet

AOTE DCC
RELEASE

台湾奥特半导体科技有限公司

TAIWAN AOTE SEMICONDUCTOR TECHNOLOGY CO.,LTD

[www . aote se mi . co m](http://www.aotese mi .co m)

概述 Description

AT815系列结合了AlGaAs红外发射二极管作为发射器，该二极管与塑料DIP4封装中的硅平面达林顿光电晶体管探测器光学耦合，具有不同的引线形成选项。AT815系列采用坚固的共面双模结构，提供最稳定的隔离。

The AT815 series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar darlington hototransistordetector in a plastic DIP4 package with different lead forming options. With the robust coplanar double mold structure, AT815 series provide the most stable isolation.

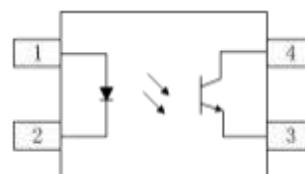
特性 Features

- 电流转换比(CTR)范围: 200% ~600% ($I_F = 5\text{mA}$, $V_{CE} = 5\text{V}$, $T_a = 25^\circ\text{C}$)
Current transfer ratio: 200% ~600% ($I_F = 5\text{mA}$, $V_{CE} = 5\text{V}$, $T_a = 25^\circ\text{C}$)
- 输入-输出隔离电压 ($V_{ISO} = 5000 \text{ Vrms}$)
High isolation voltage between input and output ($V_{ISO} = 5000 \text{ Vrms}$)
- 集电极-发射极击穿电压 $BV_{CEO} \geq 80\text{V}$
Collector - emitter breakdown voltage $BV_{CEO} \geq 80\text{V}$
- 工作温度 : $-55^\circ\text{C} \sim 110^\circ\text{C}$
Operating Temperature: $-55^\circ\text{C} \sim 110^\circ\text{C}$
- 符合加强绝缘标准
Meet reinforced insulation standards
- 符合安规标准 : UL 1577 , VDE DIN EN60747-5-5 (VDE 0884-5) , CQC11-471543-2022
Meet safety standard approval: UL 1577, VDE DIN EN60747-5-5 (VDE 0884-5) , CQC11-471543-2022

应用 Applications

- 顺序控制器
Sequence controller
- 工业控制 , 测量仪器
Industrial control, measuring instruments
- 电话/传真
Telephone/FAX
- 系统设备、测量仪器
System appliances, measuring instrument
- 编程逻辑控制器
Programmable logic controller

封装和原理图 packageandschematic Diagram



Pin Configuration

1. Anode
2. Cathode
3. Emitter
4. Collector



产品型号命名规则 Order code

AT 815 - UN Y-WV (ZZ)

① ② ③ ④ ⑤ ⑥ ⑦

- ① 公司代码 Company Code (AT: 奥特 Aote)
- ② 产品系列 Product Series (815: 815)
- ③ CTR 档位 Classification (代码 Code: C or D)
- ④ 框架类型 Lead Frame (Cu: 铜框架 Copper, Fe: 铁框架 Ferrum)
- ⑤ 树脂类型 Epoxy Type (H:树脂类型 I, L: 树脂类型 II)
- ⑥ 封装形式 Package (D:DIP, S:SMD, M:DIP-M)
- ⑦ 细分档位 Subdivison Code (T: D1 , Y: D2)
- ⑧ 内部补充代码 Internal Supplementary Code (数字或者空白 Number or None)

印字信息 Marking Information

- 印字中 “” 为奥特品牌 LOGO
“” denotes LOGO
- 印字中 “Y” 代表年份； A(2018),B(2019),C(2020)
“Y” denotes YEAR： A(2018), B(2019), C(2020)
- 印字中 “WW” 代表周号
“WW” denotes Week’ s number
- 印字中 “E” 代表内部代码
“E” denotes Internal code
- 印字中的 “H” 代表无卤
“H” denotes Halogen-free



绝缘和安规信息 Insulation and safety related specifications

项目 Item	符号 Symbol	数值 Value	单位 Unit	备注 Remark
爬电距离 Creepage Distance	L	>7.0	mm	从输入端到输出端，沿本体最短距离路径 Measured from input terminals to output terminals, shortest distance path along body
电气间隙 Clearance Distance	L	>7.0	mm	从输入端到输出端，通过空气的最短距离 Measured from input terminals to output terminals, shortest distance through air
绝缘距离 Insulation Thickness	DTI	>0.4	mm	发射器和探测器之间的绝缘厚度 Insulation thickness between emitter and detector
峰值隔离电压 Peak Isolation Voltage	V_{IORM}	1500	V_{peak}	DIN/EN/IEC EN60747-5-5
瞬态隔离电压 Transient isolation voltage	V_{IOTM}	7000	V_{peak}	DIN/EN/IEC EN60747-5-5
隔离电压 Isolation Voltage	V_{iso}	>5000	V_{rms}	For 1 min, RH < 60%

极限参数 Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

参数 Parameter		符号 Symbol	额定值 Rating	单位 Unit
发射端 Input	正向电流 Forward Current	I_F	60	mA
	峰值正向电流(1 μs , 脉冲) Peak forward current (1 μs , pulse)	I_{FP}	1000	mA
	反向电压 Reverse Voltage	V_R	6	V
	功耗 Power Dissipation	P_D	100	mW
接收端 output	集电极功耗 Collector Power Dissipation	P_C	150	mW
	集电极电流 Collector Current	I_C	80	mA
	集电极-发射极电压 Collector-Emitter Voltage	V_{CEO}	40	V
	发射极-集电极电压 Emitter - Collector Voltage	V_{ECO}	6	V
总功耗 Total Power Dissipation	P_{tot}	200	mW	
隔离电压 Isolation Voltage	V_{iso}	5000	V_{rms}	
工作温度 Operating Temperature	T_{opr}	-55 ~ +110	$^\circ\text{C}$	
存储温度 Storage Temperature	T_{stg}	-55 ~ +125	$^\circ\text{C}$	
焊接温度 Soldering Temperature	T_{sol}	260	$^\circ\text{C}$	

产品特性参数 Electro-optical characteristics (Ta=25°C)

参数 Parameter		符号 Symbol	条件 Condition	最小 Min.	典型 Typ.	最大 Max.	单位 Unit
发射端 Input	正向电压 Forward Voltage	V _{F1}	I _F = 10mA	1.0	-	1.3	V
	正向电压 Forward Voltage	V _{F2}	I _F = 20mA	1.1	-	1.4	V
	反向电流 Reverse Current	I _R	V _R = 5V	-	-	10	μA
	终端电容 Terminal Capacitance	C _t	V=0, F = 1kHz	-	30	250	pF
接收端 Output	集电极暗电流 Collector Dark Current	I _{CEO}	V _{CE} = 50V	-	-	100	nA
	集电极-发射极击穿电压 Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C = 0.1mA, I _F = 0	40	-	-	V
	发射极-集电极击穿电压 Emitter-Collector Breakdown Voltage	BV _{ECO}	I _E = 10μA, I _F = 0	6	-	-	V
传输特性 Transfer Characteristics	电流传输比 Current Transfer Ratio	CTR*	I _F = 5mA, V _{CE} = 5V	600	-	7500	%
	集电极-发射极饱和压降 Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _F = 1mA, I _C = 1mA	-	0.8	1.0	V
	隔离电阻 Isolation Resistance	R _{ISO}	DC500V, 40 ~ 60% R.H.	10 ¹²	10 ¹⁴	-	Ω
	隔离电容 Isolation capacitance	C _{ISO}	V=0, F=1MHz	-	0.6	1.0	pF
	截至频率 Cut-off Frequency	F _C	V _{CE} = 5V, I _C = 2mA, R _L = 100Ω, -3dB	-	1	-	KHz
	上升时间 Rise Time	T _r	V _{CE} = 10V, I _C = 2mA, R _L = 100Ω	-	95	300	μs
下降时间 Fall Time	T _f	V _{CE} = 10V, I _C = 2mA, R _L = 100Ω	-	84	250	μs	

注* : 电流传输比 = I_C/I_F × 100%.

Note* : CTR = I_C/I_F × 100%.

典型光电特性曲线 Typical Electro-optical characteristics curves

Fig.1 Current Transfer Ratio vs. Forward Current

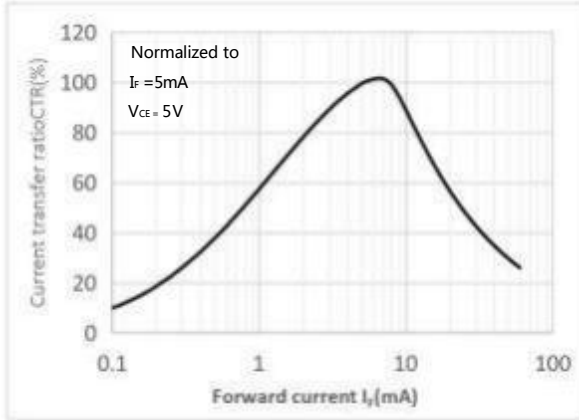


Fig.2 Forward Current vs Forward Voltage

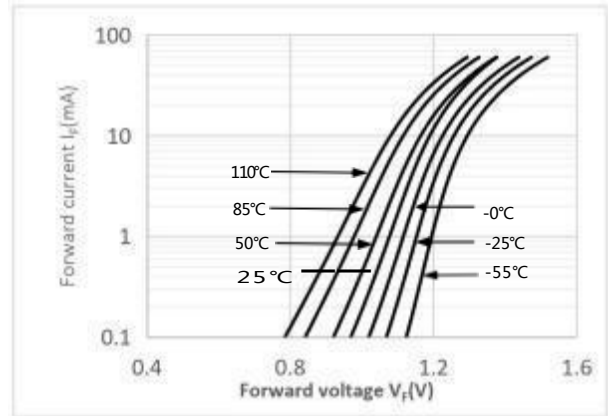


Fig.3 Collector Current vs. Collector-emitter Voltage

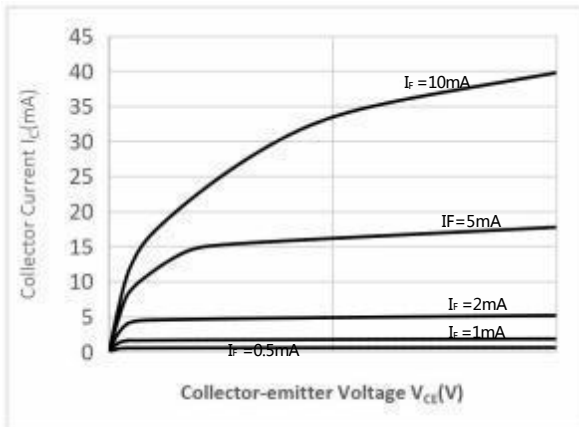


Fig.4 Relative Current Transfer Ratio vs. Ambient Temperature

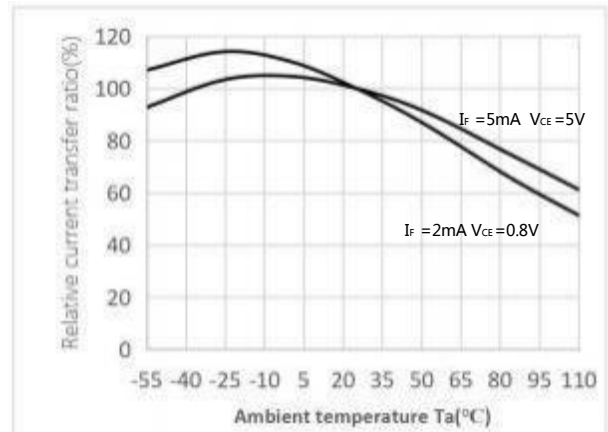


Fig.5 Collector-emitter Saturation Voltage vs. Ambient Temperature

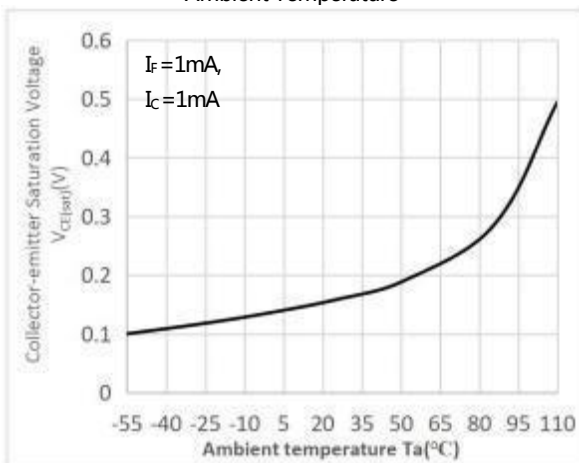


Fig.6 Collector Dark Current vs Ambient Temperature

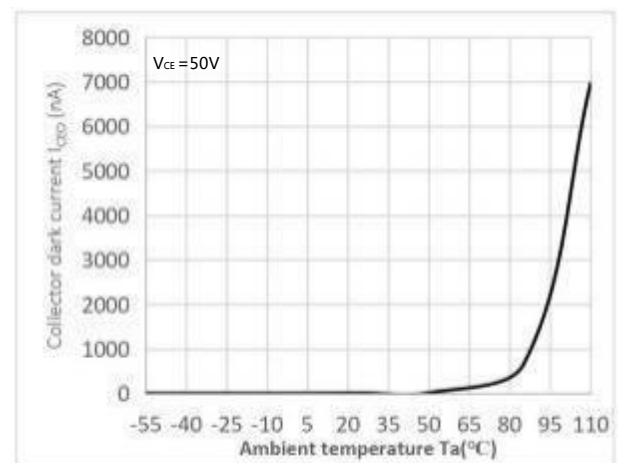


Fig.7 Response Time vs. Load Resistance

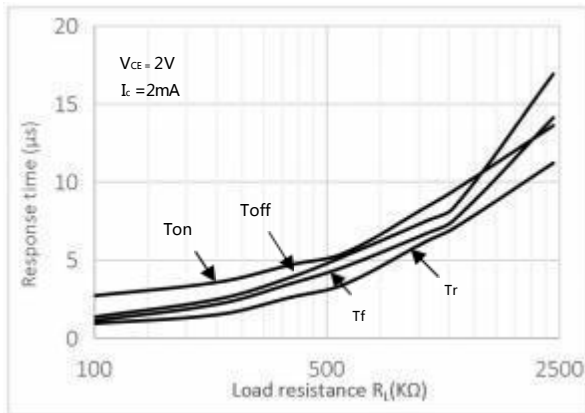


Fig.8 Frequency Response

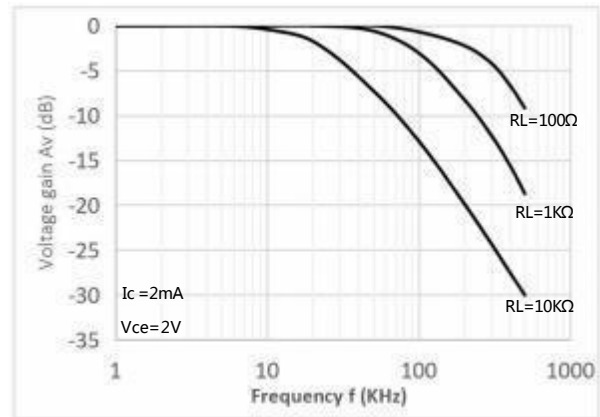


Fig.9 Collector-emitter Saturation Voltage vs. Forward Current

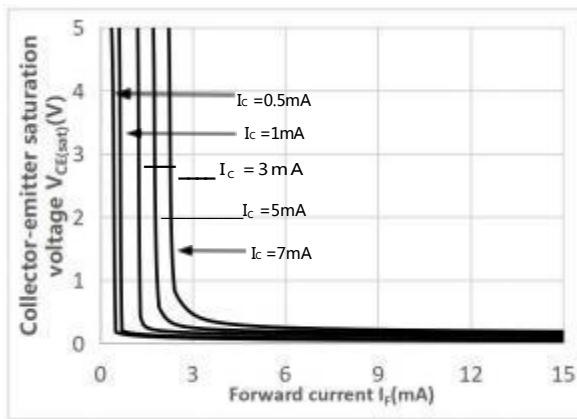
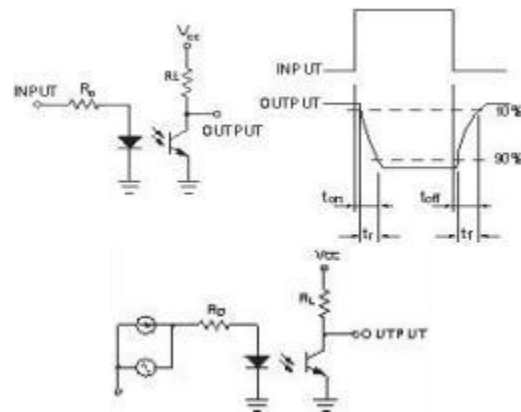
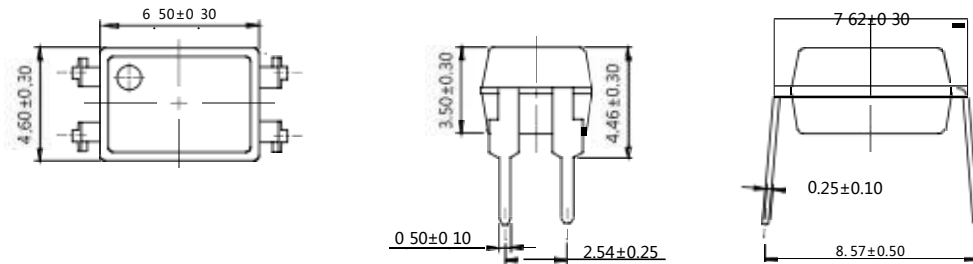


Fig.10 Test Circuits

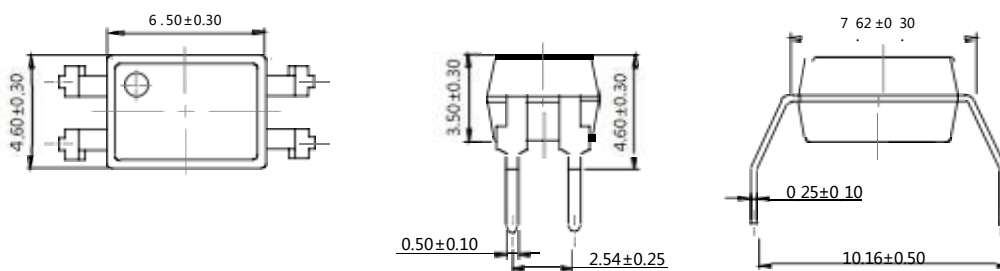


外形尺寸。utlineDimensions

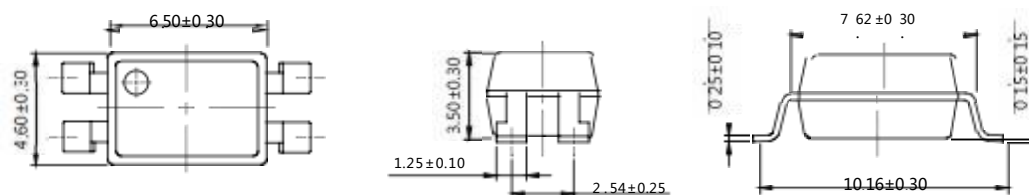
DIP4



DIP4-M

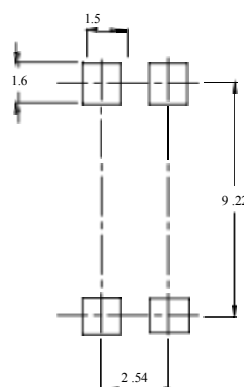


SMD4



单位 Unit: mm

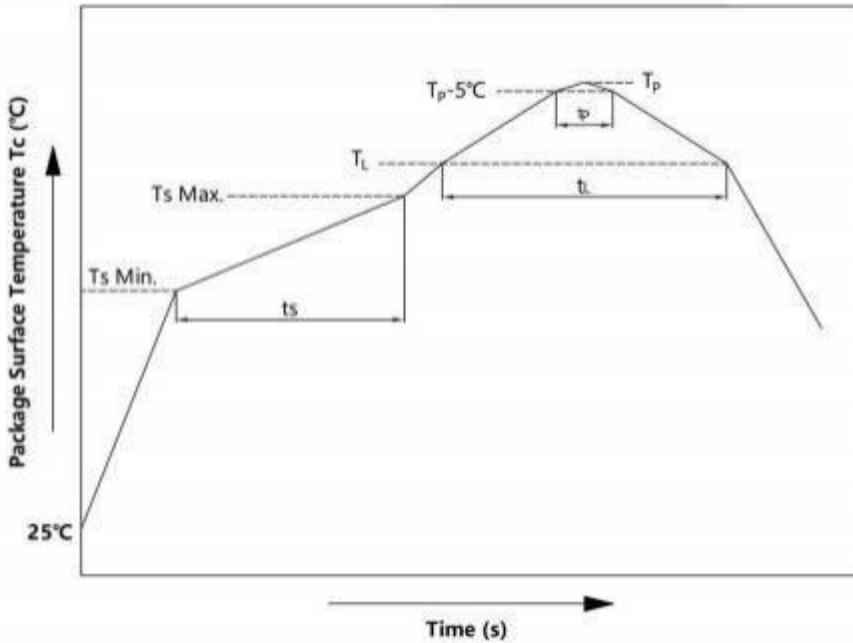
建议焊盘布局 Recommended pad Layout



单位 Unit: mm

注：上图为产品正视图。

Note: The picture above is the front view of the product.

回流焊温度曲线图 solderReflowprofile


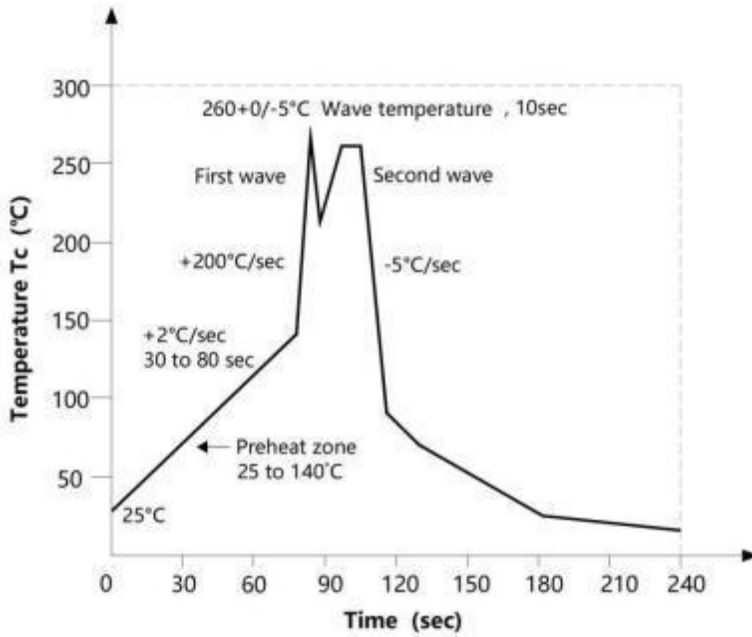
项目 Item	符号 Symbol	最小值 Min.	最大值 Max	单位 Unit
预热温度 Preheat Temperature	Ts	150	200	°C
预热时间 Preheat Time	ts	60	120	s
升温速率 Ramp-Up Rate (T _L to T _P)	-	-	3	°C/s
液相线温度 Liquidus Temperature	T _L	217		°C
时间高于 T _L Time Above T _L	t _L	60	150	s
峰值温度 Peak Temperature	T _P	-	260	°C
T _c 在(T _P -5)和 T _P 之间的时间 Time During Which T _c Is Between (T _P -5) and T _P	t _p	-	30	s
降温速率 Ramp-down Rate(T _P to T _L)	-	-	6	°C/s

注 Note :

建议在所示的温度和时间条件下进行回流焊，最多不能超过三次；

Reflow soldering is recommended at the temperatures and times shown, no more than three times;

波峰焊温度曲线图 wavesoldering profile



手工烙铁焊接 solderswith handsolderingiron

- A. 手工烙铁焊仅用于产品返修或样品测试；
Hand soldering iron is only used for product rework or sample testing;
- B. 手工烙铁焊要求：温度 $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$ ，时间 $\leq 3\text{s}$ 。
Hand soldering iron requirements：Temperature： $360^{\circ}\text{C} \pm 5^{\circ}\text{C}$, within 3s.

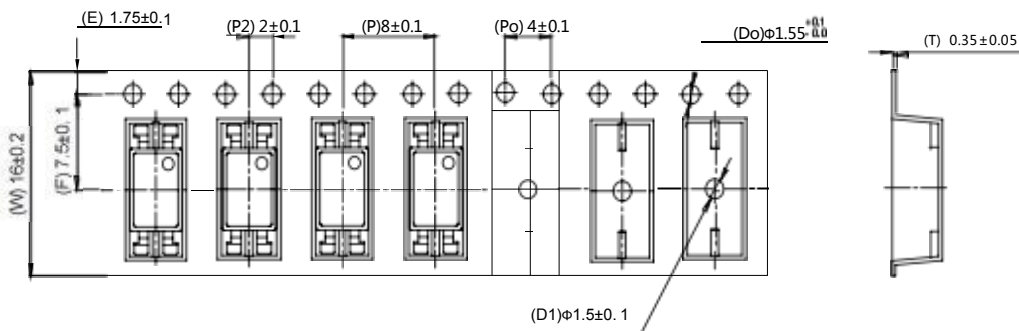
包装 packing

■ 汇总表summarytable

封装形式	包装方式	盘数量	盒数量	箱数量	静电袋规格	盒规格	箱(双瓦楞)规格	备注
SMD4	卷盘 ($\phi 330\text{mm}$ 蓝盘)	2000只/盘	2盘/盒	10盒/箱	450*390*0.1mm	340*60*340mm	620*360*365mm	首尾端空至少200mm
DIP4	管装 (500*12*11mm)	100只/管	50管/盒	10盒/箱	不适用	525*128*56mm	535*275*300mm	每管使用蓝白胶塞，方向须一致
DIP4-M	管装 (500*13*11mm)	100只/管	50管/盒	10盒/箱	不适用	525*136*58mm	535*295*310mm	
Package Type	Packing Form	Quantity per Reel	Quantity per Box	Quantity per Carton	Antistatic Bag Specification	Box Specification	Carton Specification	Note
SMD4	Reel ($\phi 330\text{mm}$ Blue)	2000 pcs/reel	2 reels/box	10 boxes/ctn	450*390*0.1mm	340*60*340mm	620*360*365mm	Leave at least 200mm of blank space at both ends
DIP4	Tube (500*12*11mm)	100 pcs/tube	50 tubes/box	10 boxes/ctn	NA	525*128*56mm	535*275*300mm	Use blue and white rubber plugs for each tube in the same direction
DIP4-M	Tube (500*13*11mm)	100 pcs/tube	50 tubes/box	10 boxes/ctn	NA	525*136*58mm	535*295*310mm	

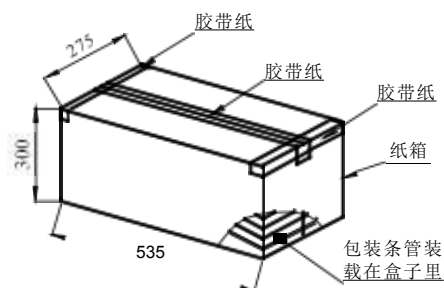
■ 编带包装Tape&Reel

- 1) 每卷数量：2000只。
Qty/reel：2000 pcs.
- 2) 每箱数量：40000只。
Qty/ctn：40000 pcs.
- 3) 内包装：每盒2盘。
Inner packing：2 reels/box.
- 4) 示意图 Schematic：



■ 管条包装Tape&Tube

- 1) 每管数量：100只。
Qty/Tube：100 pcs.
- 2) 每箱数量：50000只。
Qty/ctn：50000 pcs.
- 3) 内包装：每盒50管。
Inner packing：50 Tube/box.
- 4) 示意图 Schematic：



单位/Unit：mm

注意 Attention

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